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# RJK4513DPE

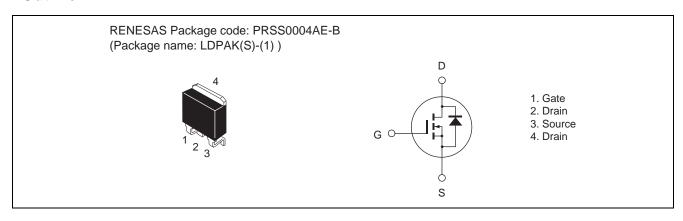
# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1586-0100 Rev.1.00 Dec 08, 2009

### **Features**

- Low on-resistance  $R_{DS(on)} = 0.33 \Omega \text{ typ. (at } I_D = 8 \text{ A, } V_{GS} = 10 \text{ V, } Ta = 25 ^{\circ}\text{C})$
- Low leakage current
- High speed switching

## **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	450	V
Gate to source voltage	$V_{GSS}$	±30	V
Drain current	I <sub>D</sub>	16	А
Drain peak current	I <sub>D (pulse)</sub> Note1	48	А
Body-drain diode reverse drain current	I <sub>DR</sub>	16	Α
Body-drain diode reverse drain peak current	I <sub>DR</sub> (pulse)	48	А
Avalanche current	I <sub>AP</sub> Note3	4	Α
Avalanche energy	E <sub>AR</sub> Note3	0.9	mJ
Channel dissipation	Pch Note2	100	W
Channel to case thermal impedance	θch-c	1.25	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at Tc = 25°C

3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C

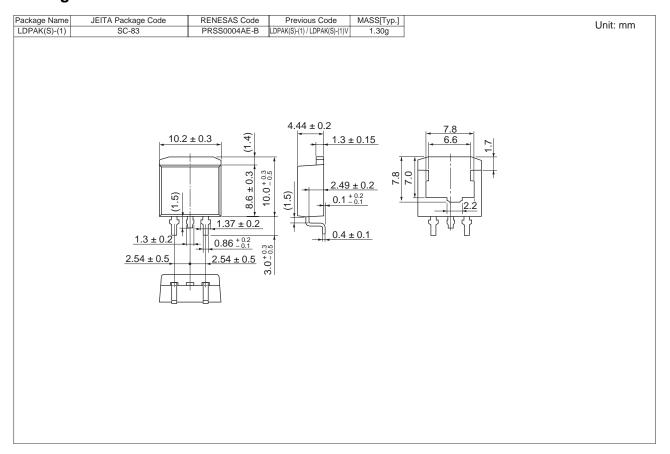
# **Electrical Characteristics**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	450		_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 450 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	3.0	_	4.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	0.33	0.38	Ω	$I_D = 8 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	1450	_	pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	162	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	18	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	33	_	ns	$I_D = 8A$ $V_{GS} = 10 \text{ V}$ $R_L = 28.1 \Omega$ $Rg = 10 \Omega$
Rise time	t <sub>r</sub>	_	28	_	ns	
Turn-off delay time	t <sub>d(off)</sub>	_	84	_	ns	
Fall time	t <sub>f</sub>	_	17	_	ns	
Total gate charge	Qg	_	37.1	_	nC	V <sub>DD</sub> = 360 V
Gate to source charge	Qgs	_	7.5	_	nC	V <sub>GS</sub> = 10 V I <sub>D</sub> = 16 A
Gate to drain charge	Qgd	_	16.9	_	nC	
Body-drain diode forward voltage	$V_{DF}$	_	0.89	1.50	V	$I_F = 16 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	290	_	ns	$I_F = 16 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

Notes: 4. Pulse test

# **Package Dimensions**



# **Ordering Information**

Part No.	Quantity	Shipping Container
RJK4513DPE-00-J3	1000 pcs	Taping

Renesas Technology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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#### Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2377-3473

**Renesas Technology Taiwan Co., Ltd.** 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510